We drive efficiency in drives
Our expertise for your optimal drive systems

Dec, 2020
Agenda

1. Introduction
2. A closer look on inverter solutions
3. Product solutions overview
4. Benefits with Silicon Carbide solutions (SiC)
5. IGBT7 technology – features and benefits
6. Key take-aways
7. Further information and links
Specific drives applications and motor types in the industry

**Industrial Drives**
- Low voltage drives
  - General purpose drives
  - Servo drives
  - C-HVAC
- Medium voltage drives

**Industrial motor types**
- Induction motor
- Switched reluctance motor
- Permanent magnet synchronous motor
- Servo motor
- Brushed DC motor
- Brushless DC motor

**Industrial automation**
- Industrial automation
Overview of three major areas in low voltage drives

<table>
<thead>
<tr>
<th>General and purpose drives</th>
<th>Servo drives</th>
<th>C-HVAC</th>
</tr>
</thead>
<tbody>
<tr>
<td>370 W</td>
<td>315 kW</td>
<td>3 kW</td>
</tr>
<tr>
<td>1250 kW</td>
<td></td>
<td>75 kW</td>
</tr>
</tbody>
</table>

### Requirements

- **General and purpose drives**
  - Performance and reliability
  - Safety features
  - Good price / performance ratio

- **Servo drives**
  - High positioning accuracy
  - Fast response with no overshoot
  - High reliability

- **C-HVAC**
  - Good price / performance ratio

### Key applications

- **General and purpose drives**
  - Pumps & fans
  - Process automation
  - Cranes
  - Marine drives

- **Servo drives**
  - Robotics
  - Material handling
  - Machine tools

- **C-HVAC**
  - Commercial Heating & Ventilation Air-Conditioning (C-HVAC)

### Infineon products

- **General and purpose drives**
  - iMOTION™
  - CIPOS™ IPM
  - EiceDRIVER™ gate driver
  - EasyPIM™
  - EconoPIM™
  - EconoDUAL™
  - PrimePACK™
  - CoolSiC™ MOSFETs

- **Servo drives**
  - CIPOS™ IPM
  - Discretes
  - EiceDRIVER™ gate driver
  - EconoPACK™
  - EasyPACK™
  - EconoDUAL™
  - CoolSiC™ MOSFETs

- **C-HVAC**
  - CIPOS™ IPM
  - EasyPIM™
  - EiceDRIVER™ gate driver
  - EconoPIM™
  - EasyPIM™
  - EiceDRIVER™ gate driver
  - CIPOS™ IPM
  - CoolSiC™ MOSFETs
Overview of medium voltage drives

<table>
<thead>
<tr>
<th>Medium voltage drives</th>
</tr>
</thead>
<tbody>
<tr>
<td>250 kW</td>
</tr>
<tr>
<td>36 MW</td>
</tr>
</tbody>
</table>

Requirements

- Long life cycle
- Fast repair
- Redundancy
- High efficiency

Key applications

- Water pumps
- Material handling
- Power generation
- Oil & gas

Infineon products

- PrimePACK™
- PrimePACK™ .XT
- XHP™ 2
- XHP™ 3
- EconoDUAL™
- 62mm
- EiceDRIVER™ gate driver
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4. Benefits with Silicon Carbide solutions (SiC)
5. IGBT7 technology – features and benefits
6. Key take-aways
7. Further information and links
Key questions to design your drives inverter

1. What is your specific application?
2. What is the RMS current/motor power?
3. What is the topology?
4. What is the voltage AC/DC?
5. What is the switching frequency?
A closer look to a typical converter system
# The levels of integration

## Power electronics
- Discretes
- 3-phase PIM
- Sixpack
- Dual switch
- Single switch
- Thyristors & Diode Discs

## Gate drivers
- Level shift driver
  - High side
  - Half bridge
  - High and low side
  - Three phase
- Isolated driver (1 & 2 channel)
- Low side driver (1 & 2 channel)

## Microcontrollers
- XMC™ controller family based on ARM® Cortex®-M
- Countless possibilities for motor control
- PSoc® 6 microcontroller

## Wireless connectivity
- Wi-Fi MCUs

## Sensor
- Magnetic sensor for position and speed
- Current sensor

## External memory
- High-Performance Memories for Embedded Systems
  - Flash
  - RAM
# Application requirements for general purpose, servo and C-HVAC drives

<table>
<thead>
<tr>
<th></th>
<th>General purpose drives</th>
<th>Servo drives</th>
<th>C-HVAC</th>
</tr>
</thead>
<tbody>
<tr>
<td><strong>Power</strong></td>
<td>Broad portfolio (0.37... 1250 kW)</td>
<td>Less broad portfolio (... ~315 kW or customized current classes)</td>
<td>Portfolio (3 kW to 75 kW)</td>
</tr>
<tr>
<td></td>
<td>600 V, 1700 V and 1200 V switches (major)</td>
<td>600 V, 1200 V switches (major)</td>
<td>1200 V switches</td>
</tr>
<tr>
<td><strong>f\textsubscript{sw}</strong></td>
<td>4 to 8 kHz &lt;100 kW 2 to 4 kHz &gt;100 kW</td>
<td>4 to 8 kHz, 16 kHz w/ derating</td>
<td>4 to 8 kHz</td>
</tr>
<tr>
<td><strong>dv/dt</strong></td>
<td></td>
<td>≤ 5 kV/µs</td>
<td></td>
</tr>
<tr>
<td><strong>SC</strong></td>
<td></td>
<td>Fast short circuit detection (e.g. 8 µs for IGBT)</td>
<td></td>
</tr>
</tbody>
</table>
| **f\textsubscript{out}** | a) Light duty – 50/60 Hz  
b) Heavy duty 1Hz w/ derating                            | Low f\textsubscript{out} common down to 0 Hz (locked rotor)                  | 30 Hz to 250 Hz                                                      |
| **OL**              | a) Light duty e.g. 110% I\textsubscript{N} 60 sec 100% I\textsubscript{N} 240 sec     | a) High overload e.g. 200% I\textsubscript{N} 3 sec 0% I\textsubscript{N} 7 sec | No overload / light overload                                         |
|                     | b) Heavy duty e.g. 150% I\textsubscript{N} 60 sec 100% I\textsubscript{N} 240 sec     | b) Very high overload e.g. 300% I\textsubscript{N} 0.25 sec 70% I\textsubscript{N} 3.75 sec |

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Overload ratings for low-voltage drives are key for reliability

Overload capability is the property in which, during acceleration operations, the inverter temporarily delivers a higher current than the rated current. **There are two sorts of ratings used in industrial drives:**

- **Light/Normal Duty (LD/ND)**
  - Applied in fans and pumps, since they do not require high torque at low speed and have a 110% overload rating
  - Torque vs. speed graph
  - Output current vs. time graph with 110% LD and 100% LD

- **Heavy Duty (HD)**
  - Applied in industrial automation and requires high torque at low speeds and a 150% overload rating
  - Torque vs. speed graph
  - Output current vs. time graph with 150% HD and 100% HD

- The base load current is reduced when compared to normal duty

For servo drives the overload capability can increase up to 300% of rated current.
<table>
<thead>
<tr>
<th>Number</th>
<th>Topic</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>Introduction</td>
</tr>
<tr>
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<td>4</td>
<td>Benefits with Silicon Carbide solutions (SiC)</td>
</tr>
<tr>
<td>5</td>
<td>IGBT7 technology – features and benefits</td>
</tr>
<tr>
<td>6</td>
<td>Key take-aways</td>
</tr>
<tr>
<td>7</td>
<td>Further information and links</td>
</tr>
</tbody>
</table>
Broad IPM portfolio serving power ranges from 20 W to 8 kW

- **CIPOS™ Nano**
  - For space constrained applications
  - Powering millions of personal cares and low power application

- **CIPOS™ Micro**
  - Compact solution
  - Optimized solution for low power fan & pump

- **CIPOS™ Tiny**
  - New solution for better design flexibility
  - Optimized solution for BLDC motor in HVAC

- **CIPOS™ Mini**
  - Broad range portfolio
  - Proven solution for MHA/Industrial drives

- **CIPOS™ Maxi**
  - Highest power density
  - Ruggedized Industrial drives and CAC solution
CIPOS™ Mini provides fully featured compact inverter solution with wide current range up to 30 A

Key features

- Fully isolated dual-in-line transfer molded package
- Compact body size of 36x21x3.1mm and the smallest IPM with current rating up to 30 A
- One package platform covers wide current rating from 4 A to 30 A and it allows easy & fast platform design from small to larger power.
- Two kinds of package types: DIP 36x21 with fullpack and DIP 36x21D with DCB substrate to support excellent thermal performance
- Integrated 600V TRENCHSTOP™ IGBT and rugged SOI gate driver technology with advanced protection features
- UL certified

Benefits

- High integrations (bootstrap circuit, thermistor) for easy design and saving system space
- Single platform possible from 4 A to 30 A
- Enhanced robustness of the advanced IGBT, gate driver IC technology
- Smaller package and high power density
- Two kinds of substrates provide cost efficient solution for low to medium power motor drives.
  
CIPoS™ Mini single boost PFC-integrated 3 phase inverter IPM enables system size reduction and cost improvement

**Key features**
- Fully isolated dual-in-line transfer molded package
- Excellent thermal performance with DCB substrate
- Inverter + single boost PFC in one package
- Inverter current rating: 10 / 15 / 20A
- Various PFC switching available: 20 kHz or 40 kHz (for 10 / 15 A)
- High PFC switching over 100kHz with CoolMOS™ Power MOSFET for PFC (for 20 A)
- Robust gate driver in SOI technology
- Power capability over 2 kW
- UL certified

**Exemplary schematic/topology:**

<table>
<thead>
<tr>
<th>Rated current</th>
<th>PFC Fsw 20 kHz</th>
<th>40 kHz</th>
</tr>
</thead>
<tbody>
<tr>
<td>10 A</td>
<td>IFCM10S60GD</td>
<td>IFCM10P60GD</td>
</tr>
<tr>
<td>15 A</td>
<td>IFCM15S60GD</td>
<td>IFCM15P60GD</td>
</tr>
<tr>
<td>20 A</td>
<td>IM564-X6D (over 100 kHz with CoolMOS™ for PFC)</td>
<td></td>
</tr>
</tbody>
</table>

**Benefits**
- System size reduction with PFC integration into inverter module as well as significant inductor size reduction with high PFC switching
- Cost improvement from lower BOM count, reduced assembly cost, and smaller system size
- Smaller and cheaper heatsink
- Customer can design switching performance of PFC by using external driver circuit

https://www.infineon.com/cms/en/product/power/intelligent-power-modules-ipm/im564-x6d/
CIPOS™ Maxi IPM Provide Excellent Performance with Highest Power Density in 1200 V Class for 3-Phase Motor Drive Application

DIP 36x23D

Key features

› Offers the smallest package in 1200 V IPM class
› Integrated 6 TRENCHSTOP™ IGBT 4 / CoolSiC™ MOSFET and a rugged 1200 V 6-channel SOI gate driver
› Integrated bootstrap functionality
› Over current shutdown
› Under-voltage lockout at all channels
› RFE pin with multi-functions
› An independent thermistor for temperature monitoring

Exemplary schematic/topology:

Benefits

› The smallest package size in 1200 V IPM class with high power density
› High output power up to 8 kW
› High efficiency up to 99.6%
› Enhanced robustness of gate driver technology for excellent protection
› Adapted to high switching application with lower power loss
› Simplified system design and manufacturing

<table>
<thead>
<tr>
<th>Part No.</th>
<th>Package</th>
<th>Rds(on)/Current Rating</th>
<th>Voltage Rating</th>
<th>Ver.</th>
</tr>
</thead>
<tbody>
<tr>
<td>IM818-SCC</td>
<td>DIP 36x23D</td>
<td>5 A</td>
<td>1200 V</td>
<td>IGBT 4</td>
</tr>
<tr>
<td>IM818-MCC</td>
<td>DIP 36x23D</td>
<td>10 A</td>
<td>1200 V</td>
<td>IGBT 4</td>
</tr>
<tr>
<td>IM818-LCC*</td>
<td>DIP 36x23D</td>
<td>15 A</td>
<td>1200 V</td>
<td>IGBT 4</td>
</tr>
<tr>
<td>IM828-XCC</td>
<td>DIP 36x23D</td>
<td>55 mohm / 20 A</td>
<td>1200 V</td>
<td>CoolSiC™ MOSFET</td>
</tr>
</tbody>
</table>

*) Under development
Broad discrete IGBT & SiC portfolio serving power ranges up to 20 kW

Discrete IGBT and CoolSiC™ MOSFET portfolio

- CoolSiC™ MOSFET
- TRENCHSTOP™2
- TRENCHSTOP™5
- TRENCHSTOP™Performance
- TRENCHSTOP™
Discrete solutions for industrial drives – features and benefits

<table>
<thead>
<tr>
<th>Product type</th>
<th>Input Connection</th>
<th>Product name and Family</th>
</tr>
</thead>
<tbody>
<tr>
<td>INV Switch-IGBT</td>
<td>1-phase</td>
<td>IKW50N65ET7 TRENCHSTOP™ IGBT7 or IMW65R072M1H CoolSiC™ MOSFET</td>
</tr>
<tr>
<td></td>
<td>3-phase</td>
<td>IKW40N120H3 HighSpeed DuoPack</td>
</tr>
<tr>
<td>INV Switch-SiC MOSFET</td>
<td>3-phase</td>
<td>IMW120R060M1H CoolSiC™ MOSFET</td>
</tr>
</tbody>
</table>

**Key features**

› IGBT7 T7 show:
  - Improved humidity ruggedness
  - Low saturation and forward voltage
  - High collector emitter voltage at 650 V
  - Up to 5µs Short Circuit Withstand Time

› CoolSiC™ MOSFET has:
  - Exclusive 3 µs short circuit withstand time
  - Reliability as Si power transistor by Infineon
  - Lowest total losses at the same EMI level as IGBT

**Benefits**

› CoolSiC™ MOSFET provides:
  - Minimum switching losses, maximum cooling surface area, zero-voltage turn-off, minimized PCB board space and further power density improvements

› TRENCHSTOP™ IGBT7 is best in class device in motor drive applications, where it shows:
  - up to 25% Higher Power Density or up to 15% lower temperature rise
Broad IGBT package portfolio serving current ranges from 6 A to 3 kA
TRENCHSTOP™ IGBT7 with the Easy family –
A perfect fit for platform based design of industrial drives

Key features

› The latest TRENCHSTOP™ IGBT7 and EC7 diode technology
› Lower on state voltage $V_{CE(sat)}$ and $V_f$
› Overload capability at $T_vj,op=175^\circ C$
› Enhanced controllability of $dv/dt$
› Optimized for simple driving
› All packages have same mechanical height

Benefits

› **Higher power density** and lower power losses
› Optimized for **Drives** application
› Reduced system size and **lower system cost**
› **Power extension** up to 45 kW, fit for platform based design and production

Find more for IGBT7: www.Infineon.com/IGBT7
Easy modules with CoolSiC™ MOSFET chip technology for industrial drives

Benefits

› Highest efficiency for reduced cooling effort
› Higher frequency operation
› Increased power density
› Optimized customer’s development cycle time and cost

Key features

EasyPACK™ 1B 1200 V / 4 mΩ sixpack module with CoolSiC™ MOSFET in 1200 V, NTC and PressFIT contact technology

› High current density
› Best in class switching and conduction losses
› Low inductive design
› Integrated NTC temperature sensor
› PressFIT contact technology
› RoHS-compliant modules

Exemplary schematic/topology:

EasyPACK™ FS45MR12W1M1P_B11 also available with pre-applied TIM
Econo2 & Econo3 modules – established product for broad range of applications

Key features

› Established RoHS-compliant housing concept for high volume production
› Modules with base plate for increased robustness in standard solder pins or high reliability PressFIT pins
› Available with state-of-the-art IGBT7 technology
› Numerous topologies, voltages (600V-1700V) and currents (15A-200A) for broad range of applications
› Integrated configurations includes NTC, shunt, pre-applied Thermal Interface Material (TIM), Advance H2S protection

Benefits

› High reliability and quality
› Cost-efficient
› Fast, simplified, low-cost mounting
› Design flexibility and simple integration in power electronic applications
› High power density
EconoDUAL™ 3 – 1st choice for future system designs

Key features
- Highest power cycling capability
- Excellent mechanical robustness
- Screw-type power terminals and PressFIT control pins
- TIM – pre-applied thermal interface material
- Available with integrated shunts
- NTC integration for temperature control
- Evaluation Boards to reduce design-in effort
- $T_{\text{vjiop}}$ 150°C (TRENCHSTOP™ IGBT4)
- $T_{\text{vjiop}}$ 175°C overload (TRENCHSTOP™ IGBT7)

Benefits
- Optimized thermal resistance to heat sink
- Reduced mounting effort and increased interconnection reliability
- Compact configurations with only 17 mm height
- Parallel operation enabled by a symmetrical design
- Reduced system costs
- One module fits several applications
EconoPACK™ 4

Key features

› Robustness: rugged mechanical design with ultrasonic welded and injection-molded screw terminals

› Easy assembly: pressFIT control pins and screw power terminals for completely solderless connections

› Integration: compact rectifier, chopper, 6-pack and 3-level single-phase configurations with NTC

Benefits

› **Cost advantage** compared to using 3 x 34mm modules / 62mm modules

› Allows **more compact inverters** compared to using 3 x 34mm / 3 x 62mm modules

Exemplary schematic/topology:

<table>
<thead>
<tr>
<th>Product</th>
<th>Ic (A)</th>
<th>Topology</th>
</tr>
</thead>
<tbody>
<tr>
<td>FS100R12PT4</td>
<td>100</td>
<td></td>
</tr>
<tr>
<td>FS150R12PT4</td>
<td>150</td>
<td></td>
</tr>
<tr>
<td>FS200R12PT4</td>
<td>200</td>
<td></td>
</tr>
</tbody>
</table>

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34mm and 62mm module family with its comprehensive portfolio offers more flexibility and highest reliability for successful Inverter Designs

Key features

- IGBT7 and EC7 1200V chipset
- Superior solution for frequency controlled inverter drives
- UL/CSA certification with UL1557 E83336
- Operating temperature up to 150°C
- Optimized switching characteristic
- Softness
- Existing packages with high current capability
- RoHS compliant

Benefits

- Highest power density
- Allows to increase inverter output power with same frame size
- Reduced switching losses
- Improved humidity robustness
PrimePACK™ modules enable high system performance

**Key features**
- Ultrasonic Welding between DCB and terminals for optimal mechanical and electrical interconnection
- Equal distance between the chips and the mounting positions
- Homogenous temperature distribution between the chips
- Improved thermal resistance $R_{\text{thjc}}$ by optimized chip locations
- Fast switching (E4) and soft switching chips (P4)
- Modular design optimized for paralleling
- Pre-applied Thermal Interface Material (TIM) to achieve longest lifetime
- NTC integration for temperature control
- $T_{\text{vop}}$ 150°C

**Exemplary schematic/topology:**

<table>
<thead>
<tr>
<th>Part Number</th>
<th>Voltage</th>
<th>IC [A]</th>
<th>Package</th>
<th>Topology</th>
</tr>
</thead>
<tbody>
<tr>
<td>FF450R12IE4</td>
<td>1200 V</td>
<td>450</td>
<td>PP2</td>
<td></td>
</tr>
<tr>
<td>FF600R12IE4/P4</td>
<td>600</td>
<td>PP2</td>
<td></td>
<td></td>
</tr>
<tr>
<td>FF900R12IE4/P4</td>
<td>900</td>
<td>PP2</td>
<td></td>
<td></td>
</tr>
<tr>
<td>FF1400R12IP4</td>
<td>1400</td>
<td>PP3</td>
<td></td>
<td></td>
</tr>
<tr>
<td>FF450R17IE4</td>
<td>1700 V</td>
<td>450</td>
<td>PP2</td>
<td></td>
</tr>
<tr>
<td>FF650R17IE4</td>
<td></td>
<td>650</td>
<td>PP2</td>
<td></td>
</tr>
<tr>
<td>FF1000R17IE4</td>
<td></td>
<td>1000</td>
<td>PP3</td>
<td></td>
</tr>
<tr>
<td>FF1400R17IP4</td>
<td></td>
<td>1400</td>
<td>PP3</td>
<td></td>
</tr>
</tbody>
</table>

**Benefits**
- Multiple frame sizes on single platform
- Frame size scalability
- High life time in demanding applications
- High reliability and quality
- Optimized system based costs
- High Irms/Area
- High current terminals
- Compact inverter size
Overview with performance classes for microcontroller

XMC1000
- ARM® Cortex®-M0
- CPU up to 48 MHz
- Flash: 8–200 kB
- Package: 16–64 pins

XMC4000
- ARM® Cortex®-M4F
- CPU up to 144 MHz
- Flash: 64 k–2 MB
- Package: 48–196 pins

AURIX™
- 1st generation
- 2nd generation

AURIX™ TC2x
- TriCore™
- Up to 3x multicore
- CPU up to 300 MHz
- Flash: 0.5–8 MB
- Package: 80–516 pins

AURIX™ TC3x
- TriCore™
- Up to 6x multicore
- CPU up to 300 MHz
- Flash: 1–16 MB
- Package: 100–516 pins

1) AURIX™ devices add safety and CAN FD
XMC™ microcontroller: The converter’s brain

Tasks of the controller

› IGBT control (PWM generation)
› Motor feedback sensing (current, position, speed)
› Speed, torque and position control
› Communication (industrial Ethernet, CAN…)

Solutions for industrial drives

› 32-bit ARM® Cortex™-M0 based XMC1000 family – low end
› 32-bit ARM® Cortex™-M4F based XMC4000 family – mid range
› 32-bit TriCore™ family – high end
XMC4000 microcontroller units for industrial drives

Key features

- 32-bit ARM® Cortex™-M4 core with FPU running at 80MHz to 144MHz
- Dedicated Inverter PWM generators (CCU8)
- Fast and flexible 12-bit ADC
- Interfaces for HALL sensors, encoders and resolvers
- Event Request Unit (ERU)
- EtherCAT interface
- Wide temperature range from -40°C to 125°C

Benefits

- Real-time performance combined with enhanced connectivity
- Based on the robust technology going beyond usual industrial requirements
- Motor Control Libraries and DAVE Apps for fast software development

Exemplary schematic/topology:
ISOFACE™ product family – Galvanic isolation & diagnostics integrated

8-channel switch IC

- 2.5 kV galvanic isolation
- 3.3 V µC interface (SPI, parallel)
- Diagnostics per channel:
  - Open load
  - Short to Vbb
  - Short to GND & overload
  - Over temperature
- 5-fold global diagnostics

H823V 8x 0.6 A 12 x 12 VQFN

8-channel switch ICs

- Integrated galvanic isolation
- Direct interface to µC
  - 3.3 V/5 V
  - Serial or parallel
- Short-circuit protection
- Inductive load switching
- Up to 1.2 A load current
- Integrated diagnostics:
  - Overload & short circuit

H811G 8x 0.6 A Parallel
H812G 8x 0.6 A SPI
H815G 8x 1.2 A Parallel
H816G 8x 1.2 A SPI

8-channel input ICs

8-ch. digital input ICs

- Integrated galvanic isolation
- Direct interface to µC
  - 3.3 V/5 V
  - Serial or parallel
- IEC-input types: 1/2/3

Sampling speed  Filter settings  Diagnostics
<table>
<thead>
<tr>
<th></th>
<th></th>
<th>Vbb-monitor  Wire-break</th>
</tr>
</thead>
<tbody>
<tr>
<td>IB11T</td>
<td>125 kHz</td>
<td>4 / IC</td>
</tr>
</tbody>
</table>
| IB13T  | 500 kHz| 9 / channel OK OK

2nd gen

1st gen

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ISOFACETM - Galvanic isolated high-side switches & input ICs

Key features

› Integrated galvanic isolation
› 8-channels
› Integrated clamping diode
› Programmable input filters
› Diagnostic feedback

Benefits

› Ideal for industrial applications operating at elevated temperatures
› Higher operational life-time
› Higher reliability
› Ideal for high-precision or high-speed applications
› At least 50% PCB area savings
› Inductive load switching
› Flexibility
› Over-load detection
› Strong maintenance support
Optimized OPTIGA™ product portfolio to meet security requirements

- **Security level**: High to Low
- **Feature set**: Single function, Advanced, Extensive TCG (Trusted Computing Group)

**Authentication**
- **OPTIGA™ Trust B**: e.g. authentication of nodes
- **OPTIGA™ Trust E**: e.g. certified authentication of nodes
- **OPTIGA™ Trust P**: e.g. Java for applications to be added

**Programmable**
- **OPTIGA™ Trust X**: e.g. secure communication to the cloud

**TCG standard**
- **OPTIGA™ TPM**: e.g. securing gateway functionality

**Connected device security**: OPTIGA™ Trust E, OPTIGA™ Trust B, OPTIGA™ Trust P, OPTIGA™ Trust X

**Microcontroller with security implementation**: Single function, Advanced, Extensive TCG (Trusted Computing Group)
How hardware security protects the factory

All systems in the factory need security. The use cases differ but Infineon’s OPTIGA™ products cover them all.

- **PC/Server**: OPTIGA™ TPM
- **Network**: OPTIGA™ TPM
- **PLC**: Main MCU
  - OPTIGA™ TPM
  - OPTIGA™ Trust M
- **Device Actuator**: MCU
  - OPTIGA™ Trust M
- **Device Sensor**: MCU
  - OPTIGA™ Trust M

**Security Features**:
- Mutual authentication
- Secured software update
- Secured communications
- Lifecycle management
- Boot process protection
- Stored data protection

Copyright © Infineon Technologies AG 2020. All rights reserved. Infineon Proprietary
OPTIGA™ Industrial TPM SLM9670

Key features
- Compliant to TCG 2.0 rev.1.38 specification
- Common Criteria EAL4+ Certified
- Secured key store & encryption algorithms: ECC (P-256, BN-256), RSA, AES, SHA-1, SHA-2, HMAC
- Industrial Grading
- JEDEC JESD47 Qualification
- Extended temperature range: -40°C to 105°C
- Enhanced reliability & Extended lifetime (20 years)

Benefits
- Tamper-resistant certified and standardized security chip enabling …
  - Digital Device ID (Mutual authentication)
  - Device Integrity & Secured Boot
  - Remote Software and Firmware updates
  - Secured communication
  - Secured storage of data and keys
- Enables and eases IEC 62443 certification

Exemplary schematic/topology:
**OPTIGA™ Trust M**

SLS32AIA010ML extended: -40 to +105°C

---

**Key features**

- Based on CC EAL 6+ (high) certified security controller
- X.509 certificate supported
- TRNG AIS-31 certified
- CA certificate in-field update
- Cryptography ECC, RSA, AES, SHA
- Extended temperature range: -40° to 105°C
- Extended lifetime (20 years)

**Benefits**

- Tamper-resistant security HW
  - Mutual authentication
  - Secured communications
  - Secured storage
  - Remote SW & FW updates
  - Integrity verification
- Enables and eases IEC 62443 certification
- Pre-integrated with leading cloud providers to enable zero touch on-boarding

---

Exemplary schematic/topology:

---
XENSI™ angle-sensors in electrification for drives

Key features

› Wide portfolio of magnetic position sensors
› Offering Hall, GMR, AMR and TMR sensors
› Digital and analog interfaces for angle sensors available

Benefits

› Suitable for all commutation types for motor control
› ISO ready and ISO compliant versions

Broad product portfolio for all kind of electric motor commutation types
XENSIV™ enablement examples: Infineon provides supportive material for a short time-to-market

**Documentation**
- Datasheets, product briefs, user manuals
- Updated product presentations

**Application notes**
- Joystick
- 3D Hall for multifunction knob
- 3D Hall for gearstick
- 3D Hall for linear movement
- 3D Hall for angle measurement
- And more…

**Online simulation tools**

**Evaluation tools & SW**
- Sensor-2-go kit for 3D Hall sensors incl. extensions
- Sensor-2-go kit for speed sensor & current sensor
- Shield2Go for 3D and current sensors
- Shield2Go for barometric pressure sensors
- Demo boards for radar

**Sensing toolboxes**
- Sensing toolbox for shaft sensing (end-of-shaft, integrated end-of-shaft) available
- Sensing toolbox for current sensing in work right now
- Main purpose: adapt fast to dedicated application
XENSIV™ TLI4971 - high precision coreless current sensor for industrial applications

Key features

› Magnetic coreless differential sensor
› Power package
› Best-in-class temperature and lifetime accuracy
› Easy system integration
› Protection capability for upcoming IGBT technologies

Benefits

› No hysteresis
› Overload capability
› Stray field immunity
› Very low power dissipation
› Superior system accuracy
› Support of ISO61508/ISO26262 requirements
› Simplified layout, reduced design risk
› Space and cost saving

Exemplary schematic/topology:
Gate driver portfolio serving power ranges up to 200 kW and above

- Power level:
  - 2.5 kW
  - 5 kW
  - 7.5 kW
  - 30 kW
  - 75 kW
  - 200 kW

- Voltage class:
  - 200 V
  - 600 V
  - 1200 V
  - 1700 V

- Coreless Transformer (CT)
  - Galvanically Isolation-Functional
  - UL 1577 $V_{ISO} = 2500 \text{ V(rms)}$ for 1 min

- Coreless Transformer (CT)
  - Galvanically Isolation – Reinforced/Basic
  - UL 1577 $V_{ISO} = 5000 \text{ V(rms)}$ for 1 min
  - VDE 0884-10 $V_{IORM} = 1420 \text{ V}$, $V_{IOTM} = 8000 \text{ V}$

- Level-Shift
  - Silicon On Insulator (SOI)
  - Junction Isolation (JI)
  - $V_{offset} = 100 \text{ V}, 200 \text{ V}, 500 \text{ V}, 600 \text{ V}, 660 \text{ V}, 1200 \text{ V}$

- Low side (N-ISO)

Note 1: 1EDC Compact only
Note 2: Voltage class is defined based on different driver configurations.
1. For single high-side, high- and low-side, half bridge and three phase gate drivers, voltage class is defined as switch breakdown voltage in applications.
2. For low side drivers, voltage class is defined as maximum operating range supply voltage.
3. For special cases as 1EDNx550 (1EDN-TDi), common mode rejection (CMR) voltage range up to 80 V.
## Key gate driver categories for industrial drives

### Non-Isolated GD
- **Low Voltage**

### Level-Shift GD
- **Junction Isolation (JI) & Silicon on Insulator (SOI)**
  - **Proven JI technology** trustfully used in all high-voltage gate drive applications for 20 years
  - **Infineon SOI technology** with integrated boot-strap diode, lower level-shift losses, and industry best-in-class robustness against – VS transient spikes
  - **Largest portfolio** of 200 V, 600 V, 700 V and 1200 V industry-standard gate drivers

### Isolated GD
- **Coreless Transformer**
  - **Magnetically-coupled isolation technology** provides galvanic isolation for industrial applications
  - **Strongest gate-drive output currents** (up to 10 A) reducing need for external booster circuits
  - **Reliable and accurate protection** options of precise & tight desat protection, active Miller clamp, isolation rating in different packages

### Solid-State Relay
- **Optical Safety Isolation**
  - **Optically isolated technology** provides galvanic isolation for safety applications
  - **Established** and reliable products with over 20 years of history
  - **Wide range of applications** from industrial automation to test and measurement equipment
EiceDRIVER™ Compact (including X3 Compact 1ED31xx)
Single-channel isolated gate driver with active Miller clamp or separate output

Key features

› Single channel isolated gate driver with up to 14 A (no booster required)
› Active Miller Clamp or Separate outputs
› 40 V absolute maximum output supply voltage,
› Exceptional CMTI robustness > 200 kV/μs
› 90 ns propagation delay with 30 ns input filter, 7 ns propagation delay matching
› Suitable for fast switching application
› DSO-8 150 mil (4mm creepage) & 300 mil wide-body package (8 mm creepage)
› For high voltage IGBT, MOSFET, CoolSiC™ SiC MOSFET
› Isolation capabilities & certification
  - 1ED31xxMU12H: UL 1577 certified $V_{ISO}=5.7$ kV(rms)
  - 1ED31xxMC12H: UL 1577 & VDE 0884-11, release in 2021 Q1
› Evaluation board available:
  - EVAL-1EDC20H12AH-SIC; EVAL-1EDI60I12AF
  - EVAL-1ED3121MX12H; EVAL-1ED3122MX12H; EVAL-1ED3124MX12H

Exemplary schematic/topology:

Typ. Output current

| 150 mil | 1ED3124MU12F | 1ED60N12AF | 1ED3125MU12F | 1EDI30I12MF |
| 300 mil | 1ED3123MU12H | 1ED60H12AH | 1ED3122MU12H | 1EDI30I12MH |

| Propagation delay | ±14 A | ±10 A | ±10 A | ±6 A |
| Input Filter | 90 ns | 125 ns | 90 ns | 300 ns |
| CMTI | 40 V | 40 V | 20 V |
| 200 kV/μs | 100 kV/μs | 200 kV/μs |
| 240 ns | 240 ns |

Certification

- 1EDC30I12MH

www.Infineon.com/gdCompact
Key features

› Single channel isolated gate driver with 3 / 6 / 9 A
› Active Miller clamp (clamp driver), DESAT, soft-off
› Exceptional CMTI robustness > 200 kV/μs
› Thermal shutdown
› X3 Analog configurability
  - Adjustable DESAT filter time & blanking time and soft-off current with external resistor
› X3 Digital configurability
  - Full adjustable via I2C bus: 3 address configuration, 27 parameter configuration, 16 status
  - Configurable UVLO, DESAT², TLTO, Soft-off, Miller clamp
› Isolation capabilities & certification
  - 1ED34/38x1M: UL 1577 certified $V_{iso}=5.7$ kV(rms)
  - 1ED34/38x1MC: UL 1577 & VDE 0884-11 (2021-Q1)
› DSO-16 fine pitch, 300 mil wide-body package (8 mm creepage)
› For IGBTs, MOSFETs, CoolSiC™ SiC MOSFETs

Exemplary schematic/topology:

Benefits

› X3 Analog: **Flexibility** based on register-based configuration adjustments
› X3 Digital: **Highest flexibility** introduced by register-based adjustments via I2C
› Reduction in hardware complexity with less customer product variants
› Reduction in the evaluation time with adjustable parameters for faster time-to-market.
EiceDRIVER™ half-bridge isolated gate driver (isolated only on high side) 2ED020I12-FI

Key features

› Galvanic isolation based on coreless transformer on the high side, half bridge isolated gate driver IC
› Drive up to 1200 V IGBT and n channel power MOSFET
› Interlock (shoot through protection)
› Power supply operating range from 14 V to 18 V
› Gate drive currents of +1 A / −2 A
› Dedicated Shutdown input
› Matched propagation delay for both channels (typ. 85ns propagation delay / ±25ns propagation delay mismatch)
› High dV/dt immunity
› Low power consumption
› General purpose operational amplifier
› General purpose comparator
› For High Power Constant Current Power Supply

Exemplary schematic/topology:

Value Proposition

› Best cost performance ratio product in EiceDRIVER™ Enhanced family
› General purpose operational amplifier and the comparator for current measurement and OCP reduce system cost by up to 0.15€ per half bridge
› Reduced external components enables a simpler PCB layout, faster design-in, and improved reliability

DSO-18
S25FL-L serial NOR Flash memories stores the boot code and application critical parameters even in rush environment.

- Densities 64Mb to 256Mb – voltage level 3.3V (2.7V-3.6V)
- Easy to design in due to industrial standard floating gate technology
- 4KB Uniform Sector Size / Easy to connect to most microcontrollers
- 100,000 Program/Sector Erase Cycles, minimum
- 0.30-ms Program time per 256 bytes and a 50-ms Sector Erase time
- 20 Year Data Retention, minimum
- Temperature range up to 125°C, multiple packages

---

**Key features**

- Easy to use and compliant due to Industrial Standard QSPI Interface
- Robust design with high temperature grade products
- Available in different packages and scalable densities

---

**Benefits**

<table>
<thead>
<tr>
<th>Series</th>
<th>Density</th>
<th>Device</th>
<th>SOIC-3 208 mil</th>
<th>SOIC-16 300 mil</th>
<th>WSON 4 x 4 mm</th>
<th>WSON 6 x 5 mm</th>
<th>BGA24 8 x 6 mm 6 x 6 Ball</th>
<th>BGA24 8 x 6 mm 4 x 6 Ball</th>
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<tbody>
<tr>
<td>FL-L</td>
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<td>128Mb</td>
<td>S25FL128L</td>
<td>✅</td>
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<td>✅</td>
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<tr>
<td></td>
<td>256Mb</td>
<td>S25FL256L</td>
<td>✅</td>
<td>✅</td>
<td>✅</td>
<td>✅</td>
<td>✅</td>
<td>✅</td>
</tr>
</tbody>
</table>
SemperFlash serial NOR Flash offers most flexibility, highest performance and functional safety with densities 256 Mb to 4 Gb

Key features

- ASIL-B / SIL-2 Functional safety compliance on component level
- Enhanced reliability (ECC and CRC)
- EnduraFlex™ Architecture – integrated wear leveling to optimize endurance and data retention
- Integrated diagnostic features for a safe and reliable operation
- High Speed Read Bandwidth up to 400MB/s – instant on feature
- xSPI compliant – easy to adopt to microcontroller (QSPI, OctalSPI, Hyperbus – perfect match to use with HyperRAM)

Exemplary schematic/topology:

Benefits

- Cortex M0 offers enhanced diagnose and safety features
- High speed reading for instant on
- EnduraFlex™ allows to partition the NOR Flash, reduced component count and increase reliability
- Functional safety compliant reduces certification time and shorten time-to-market
- Designed for high reliability in rough and higher temperature
- Longevity >10 years
Broad RAM product portfolio to meet performance requirements

- **F-RAM**:
  - 4Kbit to 16Mbit
  - Serial and Parallel interface
  - Instant non-volatility
  - Optimized solution for low-power data-logging

- **MoBL® SRAM**:
  - 256Kbit to 64Mbit
  - Access time: 45 ns – 70 ns
  - SER < 0.1 FIT/Mbit
  - Ultra-low standby currents for extending battery life

- **nvSRAM**:
  - 64Kbit to 16Mbit
  - Access time: 20 ns – 45 ns
  - Unlimited endurance
  - Optional features including RTC, timer and alarm

- **FAST SRAM**:
  - 256Kbit to 32Mbit
  - Access time: 10 ns – 15 ns
  - SER < 0.1 FIT/Mbit
  - Optimized solution for a high-speed cache memory

- **HyperRAM™**:
  - 64Mbit to 128Mbit
  - Serial HyperBus™ & xSPI
  - Up to 400 MB/s speeds
  - Ideal solution for a high-speed serial buffer memory

- **Performance (MB/s)**:
  - 4Kbit to 16Mbit: <5.00
  - 256Kbit to 64Mbit: 14.29
  - 64Kbit to 16Mbit: 22.22
  - 256Kbit to 32Mbit: 54.00
  - 64Kbit to 16Mbit: 66.67
  - 256Kbit to 32Mbit: 88.89
  - 64Mbit to 128Mbit: 100.00
  - >400.00

- **Interfaces**:
  - I2C
  - SPI
  - HyperBus
  - xSPI
  - QSPI

- **Expansion RAM**
  - Persistent

- **Data-logging RAM**
  - Persistent
Persistent RAM Solutions for Industrial Motor Drives: NVRAM

Key features

› nvSRAM
  - 256Kbit to 16Mbit in density
  - Parallel asynchronous interface with access speeds ≤ 45 ns
  - Unlimited read/write cycles
  - Optional RTC, watchdog timer, and clock alarm

› F-RAM
  - 4Kbit to 16Mbit in density
  - Serial interface 40/50 MHz SPI and 108 MHz QSPI
  - 10^{14} read/write cycles – virtually unlimited endurance
  - Instant non-volatility with NoDelay Write

Benefits

› Eliminate battery for power back-up from the system
› Capture real-time, mission-critical system data at high speeds
› Retain data instantly on power-loss or system shutdown
› Log data continuously over a 15-year product lifespan
› Enhance system reliability with on-chip ECC and CRC
› Design with parallel or low-pin-count serial SPI and QSPI interface
› Support wide operating voltages and temperature grades

Additionally, F-RAM technology is immune to data corruption due to magnetic fields and radiation exposure.
Persistent RAM Solutions for Industrial Motor Drives: MoBL® SRAM

**Key features**
- MoBL® SRAM with ECC
  - 4Mbit to 64Mbit in density
  - Access times: 45 ns – 55 ns
  - Parallel asynchronous interface
  - Bus-width configurations: x8, x16 and x32
  - Standby current (at 85°C) of 6.5 µA for 8Mbit, 8.0 µA for 16Mbit
  - Wide operating voltage range: 1.8V - 5.0V
  - High reliability with on-chip ECC
  - Industrial and Automotive temperature grades

**Benefits**
- Capture real-time, mission-critical system data at high speeds
- Extend system battery life with best-in-class standby currents
- Log data continuously over a 15-year product lifespan
- Realize reliable systems with soft-error rates (SER) < 0.1 FIT/Mbit
- Support wide operating voltages and temperature grades
- Design with asynchronous interface compatible with 32-bit MCUs
Volatile RAM Solutions for Industrial Motor Drives: FAST SRAM

**Key features**

- FAST Asynchronous SRAM with ECC
  - 2Mbit to 16Mbit in density
  - Fast access times: 10 ns – 15 ns
  - Parallel asynchronous interface
  - Bus-width configurations: x8, x16 and x32
  - Wide operating voltage range: 1.8V - 5.0V
  - High reliability with on-chip ECC
  - Industrial and Automotive temperature grades

**Benefits**

- Achieve data throughput up to 3.2Gb/s with a fast, expansion RAM
- Ideal for systems requiring high-speed expansion RAMs for use as a scratch-pad memory to execute control algorithms
- Realize reliable systems with soft-error rates (SER) < 0.1 FIT/Mbit
- Support wide operating voltages and temperature grades
- Design with asynchronous interface compatible with 32-bit MCUs

FAST asynchronous SRAMs with on-chip ECC have an optional PowerSnooze™ feature with a Deep-Sleep mode to save on idle currents ($I_{DS} = 15\mu A$) while operating at 10 ns access time.
Volatile RAM Solutions for Industrial HMI Systems: HyperRAM™

Exemplary schematic/topology:

Key features

- HyperRAM™
  - 64 Mbit to 128 Mbit in density
  - 200 MHz DDR, JEDEC-compliant (JESD251A) HyperBus™ and xSPI interface
  - Operating voltage support of 1.8 V and 3.0 V
  - High reliability with automotive AEC Q100 qualification
  - Industrial and Automotive temperature grades (up to 105 °C)
  - Provides Hybrid Sleep Mode, Deep Power Down Mode and Partial Memory Array Refresh to minimize power consumption

Benefits

- Achieve data throughput up to 3.2 Gb/s
- Ideal for systems requiring high-speed expansion RAMs for use as a display buffer for smooth graphics rendering
- Access both the HyperFlash™ and HyperRAM™ with only 11 control pins
- Support wide operating voltages and temperature grades
- Leverage HyperBus™ ecosystem to access IP for leading platforms
Modular Application Design Kit (MADK) CoolSiC™ MOSFET evaluation board for industrial drives

Compact and flexible 3-phase motor drive evaluation platform

CoolSiC™ MOSFET in EasyPACK™ 1B can easily tested
Modular Application Design Kit (MADK)
CoolSiC™ MOSFET evaluation board for industrial drives

<table>
<thead>
<tr>
<th>Parameters</th>
<th>Values</th>
<th>Conditions / Comments</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td>Including FS45MR12W1M1_B11 &amp; EDI20H12AH</td>
<td></td>
</tr>
<tr>
<td></td>
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<tr>
<td><strong>Input</strong></td>
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<td></td>
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<tr>
<td>Voltage</td>
<td>340 – 480 V_{rms}</td>
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<tr>
<td>Current</td>
<td>16 A_{rms}</td>
<td>Input 400 V_{AC}, Ta = 25 °C</td>
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<td><strong>DC bus voltage</strong></td>
<td>530 V – 670 V typ.</td>
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</tr>
<tr>
<td><strong>Switching frequency</strong></td>
<td>18 kHz nom</td>
<td></td>
</tr>
<tr>
<td></td>
<td>100 kHz max</td>
<td></td>
</tr>
<tr>
<td><strong>Output</strong></td>
<td></td>
<td></td>
</tr>
<tr>
<td>3ph P_{out} with mains line choke</td>
<td>11 kW max</td>
<td>Input 400 V_{AC}, f_{sw} = 18 kHz, T_a = 25 °C, T_h = 70 °C, forced convection cooling</td>
</tr>
<tr>
<td>3ph P_{out} without mains line choke</td>
<td>6 kW</td>
<td>Input 400 V_{AC}, f_{sw} = 18 kHz, T_a = 25 °C, T_h = 70 °C, forced convection cooling, limited by input current</td>
</tr>
<tr>
<td>f_{wk,nom} Current per leg at</td>
<td>16 A_{rms}</td>
<td>Input 400 V_{AC}, f_{sw} = 18 kHz, T_a = 25 °C, T_h = 70 °C, forced convection cooling</td>
</tr>
<tr>
<td>f_{wk,max} Current per leg at</td>
<td>8 A_{rms}</td>
<td>Input 400 V_{AC}, f_{sw} = 100 kHz, T_a = 25 °C, T_h = 70 °C, forced convection cooling</td>
</tr>
</tbody>
</table>

› 3ph AC-connector, EMI filter, bridge rectifier, inrush current limiter, 3ph voltage source inverter and a 3ph output for connecting the motor
› Isolated current, voltage sensing unit using ΔΣ-ADC (digital/analogue output)
› Temperature sensing circuitry
› Auxiliary power supply

Link to product page
Benefits with SiC solutions for industrial drives

**Increased performance**
- Reduction of power losses lead to higher performance
- 60% reduction @ 8 kHz compared to IGBT-based

**Higher robustness**
- 10 K lower operating temperature of heatsink
- Cooling efforts significantly reduced

**Higher power density & lower system cost**
- Heatsink can be reduced by 2/3 compared to IGBT
- Leads to a much higher system power density

---

Note: Measurements based on drive demonstrator (22 kW; 50 Hz output freq.; dv/dt <5 kV/µs; IGBT system under same conditions)
CoolSiC™ MOSFET powers the next generation of servo drives design

Advantages of SiC

› Up to 80% of total loss reduction is enabled by more than 50% switching loss reduction
› 80% reduction of low current conduction loss by resistive behavior
› CoolSiC™ enables motor and drive integration and hence, reduces the complexity of cabling

CoolSiC™ MOSFET

› Enables new levels of power density and performance
› Highest thermal conductivity
› Simpler topologies possible
› Smaller device footprint

No more need for a cooling fan since passive cooling is sufficient, therefore reducing your maintenance effort to a minimum.
Agenda

1. Introduction
2. A closer look on inverter solutions
3. Product solutions overview
4. Benefits with Silicon Carbide solutions (SiC)
5. IGBT7 technology – features and benefits
6. Key take-aways
7. Further information and links
Features and benefits of TRENCHSTOP™ IGBT7

- Enhanced controllability
- Improved diode
- Lower on state voltage
- Overload capability

Benefits
- Increased power
- Frame size jump
- Low losses
- Optimized driving
Technical features of TRENCHSTOP™ IGBT7

**Overload capability**

TRENCHSTOP™ IGBT7 allows a maximum junction temperature of 175°C where as TRENCHSTOP™ IGBT4 is limited to 150°C. It is beneficial for drives application due to the need of repetitive short overload operation.

**Controllability**

The TRENCHSTOP™ IGBT7 offers a high level of controllability to match the motor insulation requirements or EMI limitations. The controllability corresponds to the device’s ability to vary the dv/dt by adjusting the value of the gate resistor (RG).

**On state voltage**

Compared to TRENCHSTOP™ IGBT4, IGBT7 lowers on-state voltage by around 20%. This brings a significant reduction in losses to target applications, especially to industrial drives, which usually operate with moderate switching frequencies.

**Improved diode**

The EC7 emitter-controlled diode reduces the forward voltage by 100 mV relative to the previous generation EC4. This also lowers the reverse recovery losses. In addition, it improves softness, which benefits the inverter’s EMI behavior.
Technical benefits of TRENCHSTOP™ IGBT7

**Increased power**

The EconoDUAL™ 3 with TRENCHSTOP™ IGBT7 can reach up to 900 A. Benefit from higher inverter output current for the same frame size, reduced system cost by avoiding paralleling of modules.

**Low losses**

The conduction losses at the given dv/dt limitation are significantly decreased. Moreover, there is a reduction in diode losses which leads to overall 15% lower power losses.

**Frame size jump**

An application example for general-purpose drives (GPD) compares modules built with IGBT4 and IGBT7 technologies. This illustrates how power density can be increased while lowering system cost.

**Optimized driving**

CGE and CGC are balanced to give the IGBT7 full control over the dv/dt, and to optimize the switching waveform. CGE is designed to avoid parasitic turn-on effects, zero voltage supply for turn-off is feasible (unipolar gate driver power supply).
Customer benefits of IGBT7 solutions

**Plug and play**
- Pin to pin compatibility with IGBT4 module
- Lower losses
- Higher robustness

**Reduction of heatsink**
- System cost saving
- Compact inverter design

**Package Jump**
- Cost saving on module side
- Compact inverter design
- Higher flexibility on inverter frame size

**Broad portfolio**
- Will be available in a broad power range
- High volume production
## Agenda

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4. Benefits with Silicon Carbide solutions (SiC)
5. IGBT7 technology – features and benefits
6. Key take-aways
7. Further information and links
Key take-aways

Infineon offers optimized technologies
› IGBT7 perfectly matched to the needs of drives applications like overload and switching speed control
› SiC-MOSFETs enabling a high degree of integration due to low losses

Infineon has a unique one shop offering for industrial drives
› The right fit package for the inverter in power range from W with IPM’s and 100’s of kW with EconoDUAL™
› Gate Driver solutions with enhanced functionalities
› Current sense solutions
› Peripherals like industrial interface IC’s, security solutions and microcontrollers

Infineon is the right partner for customized solution and high volume products
› With outstanding quality standards and production capability
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# Useful information material and tools

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<th>Product page links</th>
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</thead>
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<td>› CIPOS™ IPM</td>
</tr>
<tr>
<td>› iMOTION™</td>
</tr>
<tr>
<td>› CoolSiC MOSFETs</td>
</tr>
<tr>
<td>› TRENCHSTOP™ IGBT7</td>
</tr>
<tr>
<td>› Easy power modules</td>
</tr>
<tr>
<td>› EconoPIM™ 2 &amp; 3</td>
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<tr>
<td>› EconoDUAL™ IGBT modules</td>
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<td>› EconoPACK™ 4</td>
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<tr>
<td>› PrimePACK™ IGBT modules</td>
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<tr>
<td>› 32-bit XMC™ microcontroller</td>
</tr>
<tr>
<td>› ISOFACE™ digital input ICs</td>
</tr>
<tr>
<td>› OPTIGA™ security solutions</td>
</tr>
<tr>
<td>› Magnetic sensors</td>
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<tr>
<td>› Current sensor</td>
</tr>
<tr>
<td>› EiceDRIVER™ gate driver</td>
</tr>
<tr>
<td>› External memory</td>
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<tr>
<td>› Wireless connectivity</td>
</tr>
<tr>
<td>› PSoC62, PSoC64</td>
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</tbody>
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## Application pages

- Overview
- Induction motor
- Permanent magnet
- Synchronized motor
- Servo motor
- Motor control for industrial automation
- Robotics

## MADK

- iMOTION™ Modular Application Design Kit MADK

## Online simulations

- IPOSIM
- Discrete IGBT Motor Drive Simulator
- IPM 3-phase Inverter Simulator

## Online forums

- Silicon Carbide forum
- IGBT modules forum
- IGBT discretes forum

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